

KSP42/43

High Voltage Transistor

- Collector-Emitter Voltage: V_{CEO}=KSP42: 300V KSP43: 200V
- Collector Power Dissipation: P_C(max)=625mW



1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector Base Voltage		
	: KSP42	300	V
	: KSP43	200	V
V _{CEO}	Collector-Emitter Voltage		
	: KSP42	300	V
	: KSP43	200	V
V_{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current	500	mA
P _C	Collector Power Dissipation	625	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0			
	: KSP42		300		V
	: KSP43		200		V
BV _{CEO}	* Collector -Emitter Breakdown Voltage	I _C =1mA, I _B =0			
	: KSP42		300		V
	: KSP43		200		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =100μA, I _C =0	6		V
I _{CBO}	Collector Cut-off Current				
	: KSP42	V _{CB} =200V, I _E =0		100	nA
	: KSP43	V _{CB} =160V, I _E =0		100	nA
I _{EBO}	Emitter Cut-off Current				
	: KSP42	$V_{BE}=6V, I_{C}=0$		100	nA
	: KSP43	$V_{BE}=4V$, $I_{C}=0$		100	nA
h _{FE}	* DC Current Gain	V _{CE} =10V, I _C =1mA	25		
		V _{CE} =10V, I _C =10mA	40		
		V _{CE} =10V, I _C =30mA	40		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =20mA, I _B =2mA		0.5	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =20mA, I _B =2mA		0.9	V
C _{ob}	Output Capacitance	V _{CB} =20V, I _E =0			
	: KSP42	f=1MHz		3	pF
	: KSP43			4	pF
f _T	Current Gain Bandwidth Product	V _{CE} =20V, I _C =10mA f=100MHz	50		MHz

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

Typical Characteristics

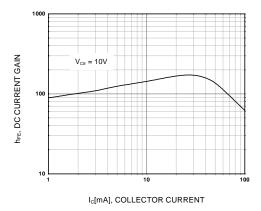


Figure 1. DC current Gain

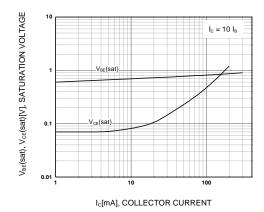


Figure 2. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

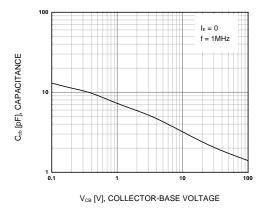


Figure 3. Collector-Base Capacitance

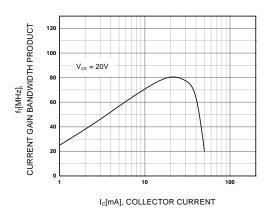
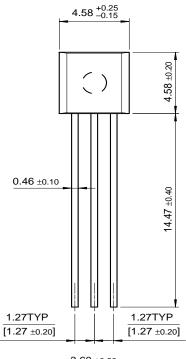
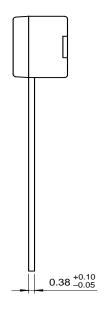


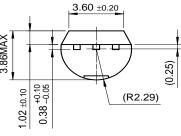
Figure 4. Current Gain Bandwidth Product

Package Dimensions

TO-92







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